

# Small Signal MOSFET

## 30 Volts

### N-Channel SC70

- We declare that the material of product are Halogen Free and compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

### FEATURES

- $R_{DS(ON)} \leq 8\Omega @ V_{GS}=4V$
- $R_{DS(ON)} \leq 13\Omega @ V_{GS}=2.5V$
- Super high density cell design for extremely low  $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability
- Capable doing Cu wire bonding
- ESD Protected:1000V

### APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- Load Switch

### ORDERING INFORMATION

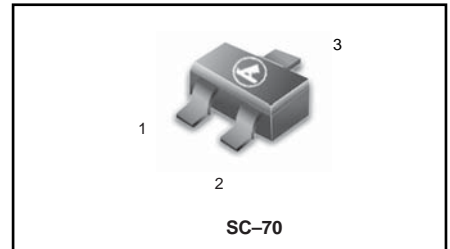
Device	Marking	Shipping
L2N7002FWT1G S-L2N7002FWT1G	7F	3000 Tape & Reel
L2N7002FWT3G S-L2N7002FWT3G	7F	10000 Tape & Reel

### THERMAL CHARACTERISTICS

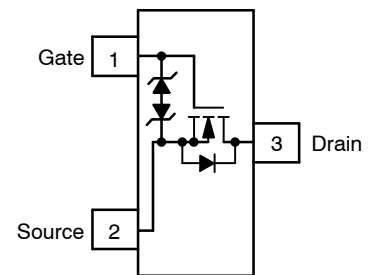
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1.) $T_A = 25^\circ C$ Derate above $25^\circ C$	$P_D$	225 1.8	mW mW/ $^\circ C$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ C/W$
Total Device Dissipation Alumina Substrate,(Note 2.) $T_A = 25^\circ C$ Derate above $25^\circ C$	$P_D$	300 2.4	mW mW/ $^\circ C$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ C/W$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ C$

1. FR-5 = 1.0 x 0.75 x 0.062 in.
2. Alumina = 0.4 x 0.3 x 0.025 in 99.5% alumina.

**L2N7002FWT1G**  
**S-L2N7002FWT1G**

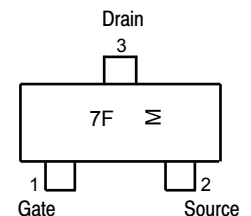


### Simplified Schematic



(Top View)

### MARKING DIAGRAM & PIN ASSIGNMENT



7F = Device Code  
M = Month Code

L2N7002FWT1G,S-L2N7002FWT1G

**Absolute Maximum Ratings** (TA=25°C Unless Otherwise Noted)

Parameter	Symbol	Maximum Ratings	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V

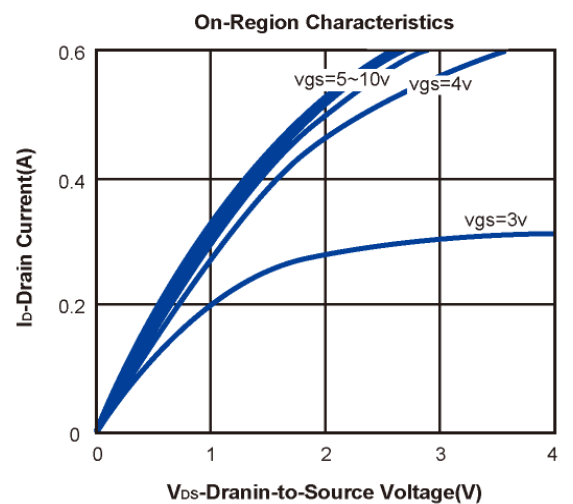
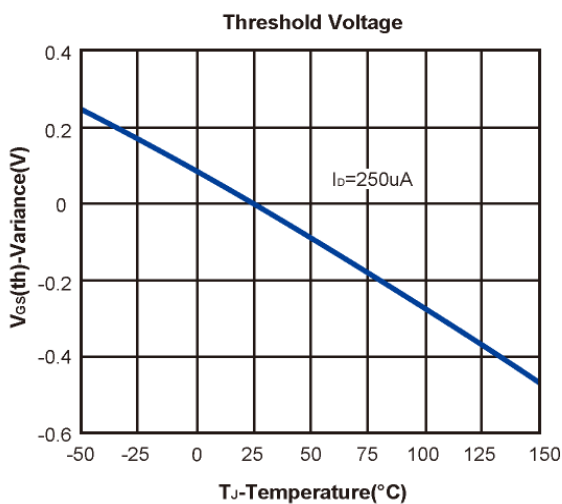
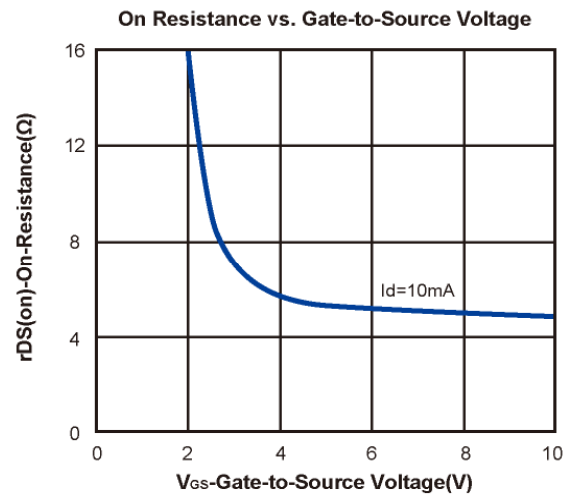
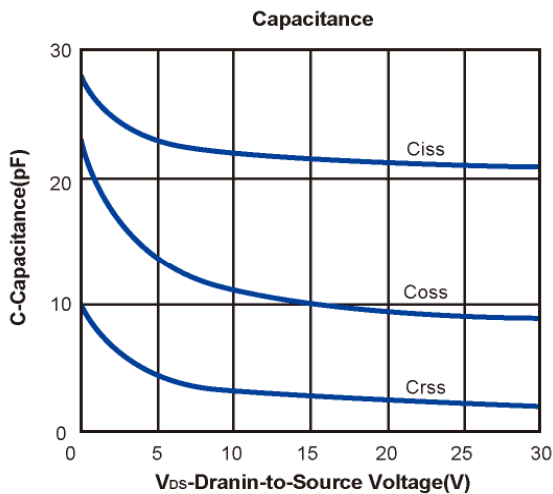
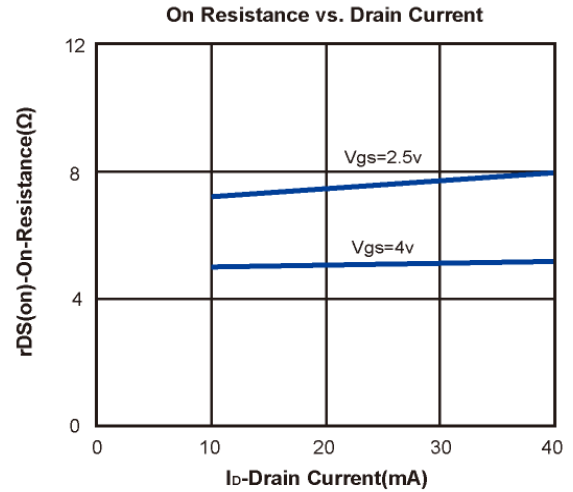
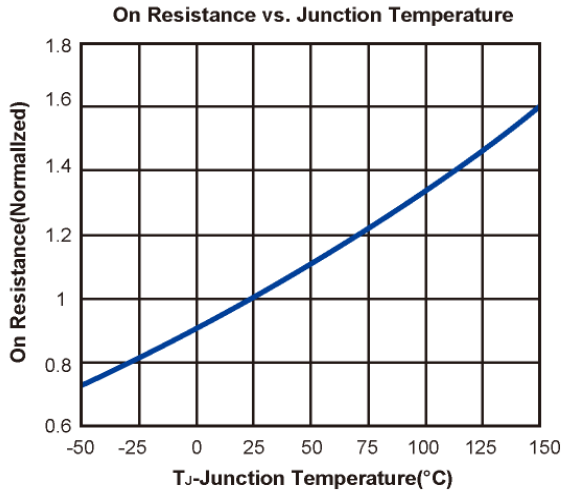
**Electrical Characteristics** (T<sub>j</sub>=25°C Unless Otherwise Specified)

Symbol	Parameter	Limit	Min	Typ	Max	Unit
<b>STATIC</b>						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250 μA	30			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250 μA	0.8		1.5	V
I <sub>GSS</sub>	Gate-Body Leakage	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±10	μA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V			1	μA
R <sub>DS(ON)</sub>	Drain-Source On-Resistance*	V <sub>GS</sub> =4V, I <sub>D</sub> =10mA		5	8	Ω
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =1mA		7	13	
V <sub>SD</sub>	Diode Forward Voltage *	I <sub>S</sub> =200mA, V <sub>GS</sub> =0V			1.2	V
<b>DYNAMIC</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =25V, V <sub>GS</sub> =10V, I <sub>D</sub> =0.22A		4.9		nC
Q <sub>gs</sub>	Gate-Source Charge			2.1		
Q <sub>gd</sub>	Gate-Drain Charge			0.6		
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHz		21		pF
C <sub>oss</sub>	Output Capacitance			10		
C <sub>rss</sub>	Reverse Transfer Capacitance			2		
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> =5V, R <sub>L</sub> =500Ω V <sub>GES</sub> =5V, R <sub>G</sub> =10Ω		10.1		ns
t <sub>r</sub>	Turn-On Rise Time			7.3		
t <sub>d(off)</sub>	Turn-Off Delay Time			31.3		
t <sub>f</sub>	Turn-Off Fall Time			28.2		

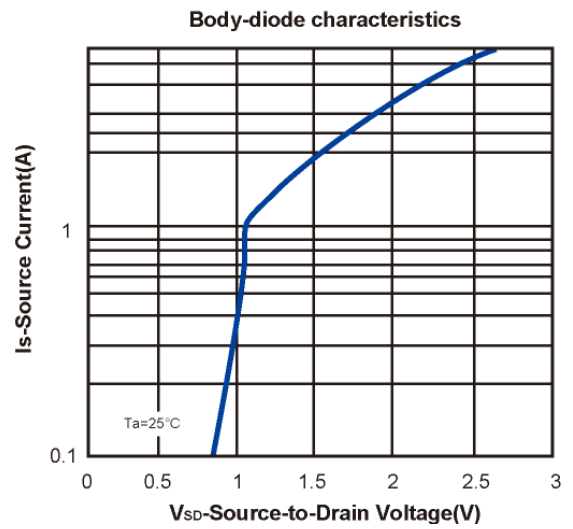
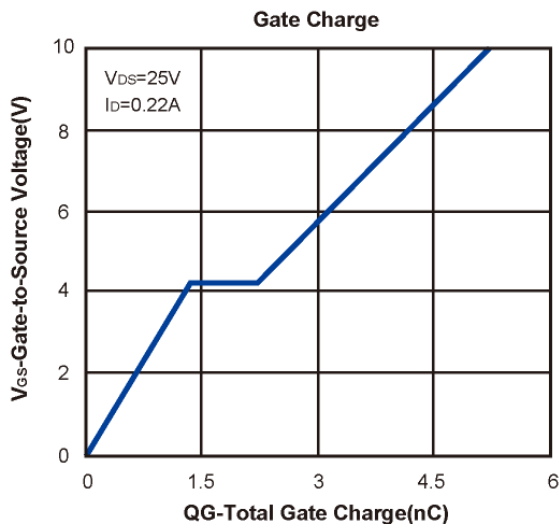
Notes: \*. Pulse test; pulse width ≤ 300us, duty cycle ≤ 2%.

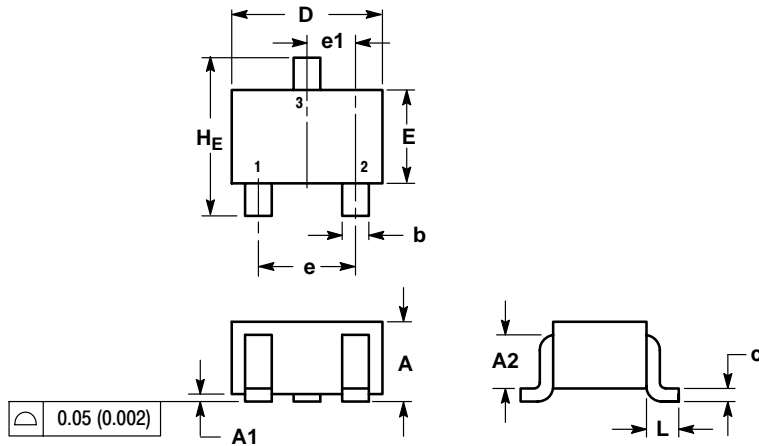
L2N7002FWT1G,S-L2N7002FWT1G

Typical Characteristics (T<sub>J</sub> =25°C Noted)



**Typical Characteristics (T<sub>J</sub> =25°C Noted)**



**L2N7002FWT1G,S-L2N7002FWT1G**
**SC-70 (SOT-323)**


DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.7 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.425 REF			0.017 REF		
H <sub>E</sub>	2.00	2.10	2.40	0.079	0.083	0.095

**SOLDERING FOOTPRINT\***
